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### Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

### Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

#### Details

Product Status	Obsolete
Number of LABs/CLBs	360
Number of Logic Elements/Cells	2880
Total RAM Bits	20480
Number of I/O	189
Number of Gates	116000
Voltage - Supply	3V ~ 3.6V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 70°C (TA)
Package / Case	240-BFQFP
Supplier Device Package	240-PQFP (32x32)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/intel/epf10k50vqc240-3aa">https://www.e-xfl.com/product-detail/intel/epf10k50vqc240-3aa</a>

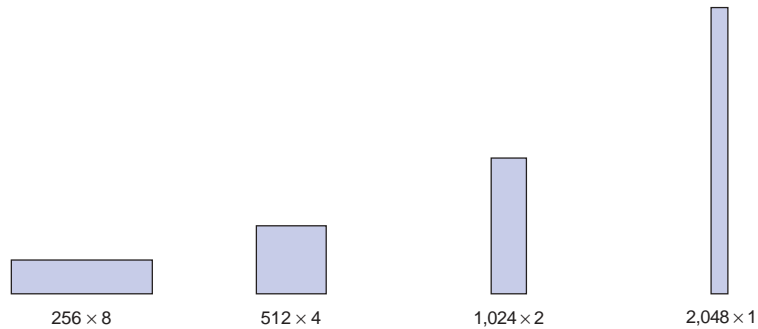
Logic functions are implemented by programming the EAB with a read-only pattern during configuration, creating a large LUT. With LUTs, combinatorial functions are implemented by looking up the results, rather than by computing them. This implementation of combinatorial functions can be faster than using algorithms implemented in general logic, a performance advantage that is further enhanced by the fast access times of EABs. The large capacity of EABs enables designers to implement complex functions in one logic level without the routing delays associated with linked LEs or field-programmable gate array (FPGA) RAM blocks. For example, a single EAB can implement a  $4 \times 4$  multiplier with eight inputs and eight outputs. Parameterized functions such as LPM functions can automatically take advantage of the EAB.

The EAB provides advantages over FPGAs, which implement on-board RAM as arrays of small, distributed RAM blocks. These FPGA RAM blocks contain delays that are less predictable as the size of the RAM increases. In addition, FPGA RAM blocks are prone to routing problems because small blocks of RAM must be connected together to make larger blocks. In contrast, EABs can be used to implement large, dedicated blocks of RAM that eliminate these timing and routing concerns.

EABs can be used to implement synchronous RAM, which is easier to use than asynchronous RAM. A circuit using asynchronous RAM must generate the RAM write enable (WE) signal, while ensuring that its data and address signals meet setup and hold time specifications relative to the WE signal. In contrast, the EAB's synchronous RAM generates its own WE signal and is self-timed with respect to the global clock. A circuit using the EAB's self-timed RAM need only meet the setup and hold time specifications of the global clock.

When used as RAM, each EAB can be configured in any of the following sizes:  $256 \times 8$ ,  $512 \times 4$ ,  $1,024 \times 2$ , or  $2,048 \times 1$ . See [Figure 2](#).

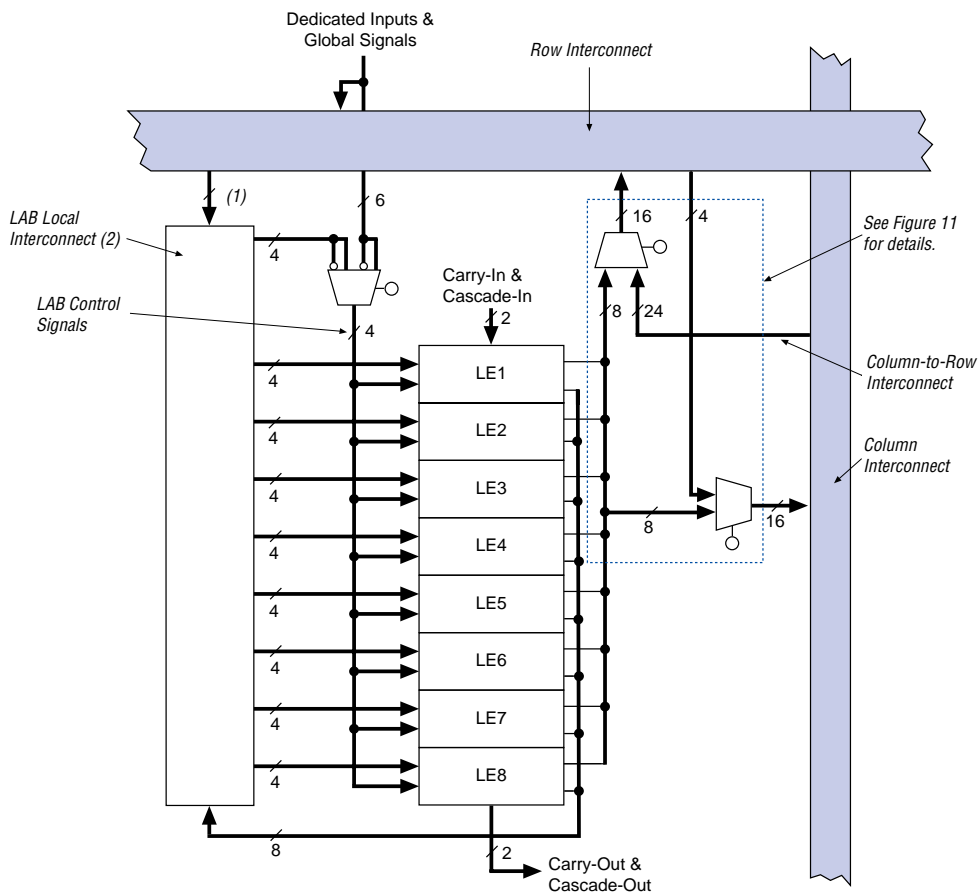
**Figure 2. EAB Memory Configurations**



## Logic Array Block

Each LAB consists of eight LEs, their associated carry and cascade chains, LAB control signals, and the LAB local interconnect. The LAB provides the coarse-grained structure to the FLEX 10K architecture, facilitating efficient routing with optimum device utilization and high performance. See [Figure 5](#).

**Figure 5. FLEX 10K LAB**



**Notes:**

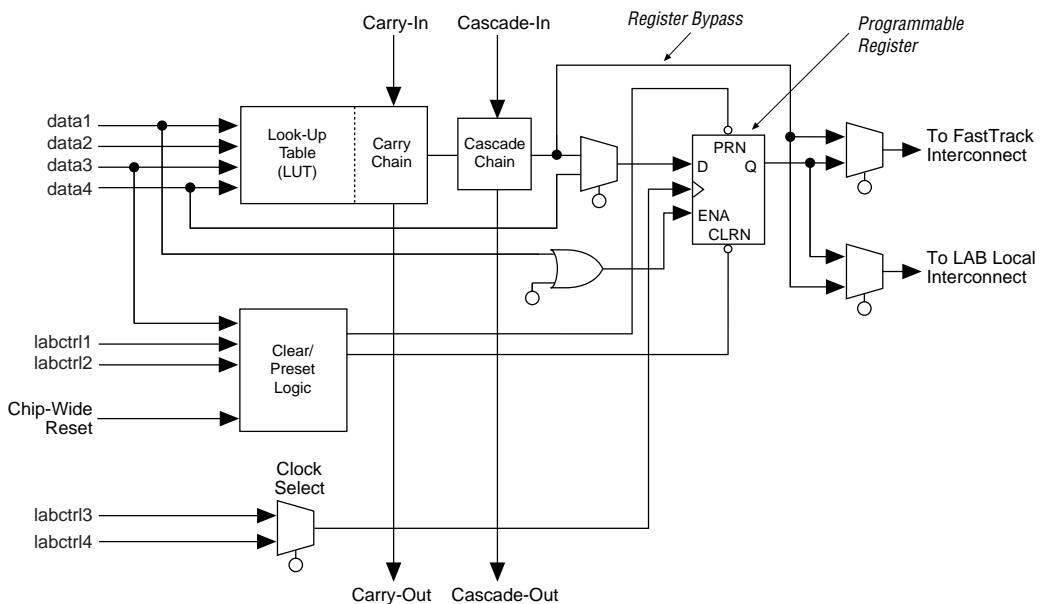
- (1) EPF10K10, EPF10K10A, EPF10K20, EPF10K30, EPF10K30A, EPF10K40, EPF10K50, and EPF10K50V devices have 22 inputs to the LAB local interconnect channel from the row; EPF10K70, EPF10K100, EPF10K100A, EPF10K130V, and EPF10K250A devices have 26.
- (2) EPF10K10, EPF10K10A, EPF10K20, EPF10K30, EPF10K30A, EPF10K40, EPF10K50, and EPF10K50V devices have 30 LAB local interconnect channels; EPF10K70, EPF10K100, EPF10K100A, EPF10K130V, and EPF10K250A devices have 34 LABs.

Each LAB provides four control signals with programmable inversion that can be used in all eight LEs. Two of these signals can be used as clocks; the other two can be used for clear/preset control. The LAB clocks can be driven by the dedicated clock input pins, global signals, I/O signals, or internal signals via the LAB local interconnect. The LAB preset and clear control signals can be driven by the global signals, I/O signals, or internal signals via the LAB local interconnect. The global control signals are typically used for global clock, clear, or preset signals because they provide asynchronous control with very low skew across the device. If logic is required on a control signal, it can be generated in one or more LEs in any LAB and driven into the local interconnect of the target LAB. In addition, the global control signals can be generated from LE outputs.

## Logic Element

The LE, the smallest unit of logic in the FLEX 10K architecture, has a compact size that provides efficient logic utilization. Each LE contains a four-input LUT, which is a function generator that can quickly compute any function of four variables. In addition, each LE contains a programmable flipflop with a synchronous enable, a carry chain, and a cascade chain. Each LE drives both the local and the FastTrack Interconnect. See [Figure 6](#).

**Figure 6. FLEX 10K Logic Element**



### Normal Mode

The normal mode is suitable for general logic applications and wide decoding functions that can take advantage of a cascade chain. In normal mode, four data inputs from the LAB local interconnect and the carry-in are inputs to a four-input LUT. The Compiler automatically selects the carry-in or the DATA3 signal as one of the inputs to the LUT. The LUT output can be combined with the cascade-in signal to form a cascade chain through the cascade-out signal. Either the register or the LUT can be used to drive both the local interconnect and the FastTrack Interconnect at the same time.

The LUT and the register in the LE can be used independently; this feature is known as register packing. To support register packing, the LE has two outputs; one drives the local interconnect and the other drives the FastTrack Interconnect. The DATA4 signal can drive the register directly, allowing the LUT to compute a function that is independent of the registered signal; a three-input function can be computed in the LUT, and a fourth independent signal can be registered. Alternatively, a four-input function can be generated, and one of the inputs to this function can be used to drive the register. The register in a packed LE can still use the clock enable, clear, and preset signals in the LE. In a packed LE, the register can drive the FastTrack Interconnect while the LUT drives the local interconnect, or vice versa.

### Arithmetic Mode

The arithmetic mode offers 2 three-input LUTs that are ideal for implementing adders, accumulators, and comparators. One LUT computes a three-input function, and the other generates a carry output. As shown in [Figure 9](#) on page 19, the first LUT uses the carry-in signal and two data inputs from the LAB local interconnect to generate a combinatorial or registered output. For example, in an adder, this output is the sum of three signals: a, b, and carry-in. The second LUT uses the same three signals to generate a carry-out signal, thereby creating a carry chain. The arithmetic mode also supports simultaneous use of the cascade chain.

### **Up/Down Counter Mode**

The up/down counter mode offers counter enable, clock enable, synchronous up/down control, and data loading options. These control signals are generated by the data inputs from the LAB local interconnect, the carry-in signal, and output feedback from the programmable register. The Up/down counter mode uses 2 three-input LUTs: one generates the counter data, and the other generates the fast carry bit. A 2-to-1 multiplexer provides synchronous loading. Data can also be loaded asynchronously with the clear and preset register control signals, without using the LUT resources.

### **Clearable Counter Mode**

The clearable counter mode is similar to the up/down counter mode, but supports a synchronous clear instead of the up/down control. The clear function is substituted for the cascade-in signal in the up/down counter mode. Clearable counter mode uses 2 three-input LUTs: one generates the counter data, and the other generates the fast carry bit. Synchronous loading is provided by a 2-to-1 multiplexer. The output of this multiplexer is ANDed with a synchronous clear signal.

### *Internal Tri-State Emulation*

Internal tri-state emulation provides internal tri-stating without the limitations of a physical tri-state bus. In a physical tri-state bus, the tri-state buffers' output enable (OE) signals select which signal drives the bus. However, if multiple OE signals are active, contending signals can be driven onto the bus. Conversely, if no OE signals are active, the bus will float. Internal tri-state emulation resolves contending tri-state buffers to a low value and floating buses to a high value, thereby eliminating these problems. The Altera software automatically implements tri-state bus functionality with a multiplexer.

### *Clear & Preset Logic Control*

Logic for the programmable register's clear and preset functions is controlled by the DATA3, LABCTRL1, and LABCTRL2 inputs to the LE. The clear and preset control structure of the LE asynchronously loads signals into a register. Either LABCTRL1 or LABCTRL2 can control the asynchronous clear. Alternatively, the register can be set up so that LABCTRL1 implements an asynchronous load. The data to be loaded is driven to DATA3; when LABCTRL1 is asserted, DATA3 is loaded into the register.

**Table 8. EPF10K10, EPF10K20, EPF10K30, EPF10K40 & EPF10K50 Peripheral Bus Sources**

Peripheral Control Signal	EPF10K10 EPF10K10A	EPF10K20	EPF10K30 EPF10K30A	EPF10K40	EPF10K50 EPF10K50V
OE0	Row A	Row A	Row A	Row A	Row A
OE1	Row A	Row B	Row B	Row C	Row B
OE2	Row B	Row C	Row C	Row D	Row D
OE3	Row B	Row D	Row D	Row E	Row F
OE4	Row C	Row E	Row E	Row F	Row H
OE5	Row C	Row F	Row F	Row G	Row J
CLKENA0/CLK0/GLOBAL0	Row A	Row A	Row A	Row B	Row A
CLKENA1/OE6/GLOBAL1	Row A	Row B	Row B	Row C	Row C
CLKENA2/CLR0	Row B	Row C	Row C	Row D	Row E
CLKENA3/OE7/GLOBAL2	Row B	Row D	Row D	Row E	Row G
CLKENA4/CLR1	Row C	Row E	Row E	Row F	Row I
CLKENA5/CLK1/GLOBAL3	Row C	Row F	Row F	Row H	Row J

**Table 9. EPF10K70, EPF10K100, EPF10K130V & EPF10K250A Peripheral Bus Sources**

Peripheral Control Signal	EPF10K70	EPF10K100 EPF10K100A	EPF10K130V	EPF10K250A
OE0	Row A	Row A	Row C	Row E
OE1	Row B	Row C	Row E	Row G
OE2	Row D	Row E	Row G	Row I
OE3	Row I	Row L	Row N	Row P
OE4	Row G	Row I	Row K	Row M
OE5	Row H	Row K	Row M	Row O
CLKENA0/CLK0/GLOBAL0	Row E	Row F	Row H	Row J
CLKENA1/OE6/GLOBAL1	Row C	Row D	Row F	Row H
CLKENA2/CLR0	Row B	Row B	Row D	Row F
CLKENA3/OE7/GLOBAL2	Row F	Row H	Row J	Row L
CLKENA4/CLR1	Row H	Row J	Row L	Row N
CLKENA5/CLK1/GLOBAL3	Row E	Row G	Row I	Row K

Table 10 lists the FLEX 10K row-to-IOE interconnect resources.

<b>Table 10. FLEX 10K Row-to-IOE Interconnect Resources</b>		
<b>Device</b>	<b>Channels per Row (<i>n</i>)</b>	<b>Row Channels per Pin (<i>m</i>)</b>
EPF10K10 EPF10K10A	144	18
EPF10K20	144	18
EPF10K30 EPF10K30A	216	27
EPF10K40	216	27
EPF10K50 EPF10K50V	216	27
EPF10K70	312	39
EPF10K100 EPF10K100A	312	39
EPF10K130V	312	39
EPF10K250A	456	57

#### *Column-to-IOE Connections*

When an IOE is used as an input, it can drive up to two separate column channels. When an IOE is used as an output, the signal is driven by a multiplexer that selects a signal from the column channels. Two IOEs connect to each side of the column channels. Each IOE can be driven by column channels via a multiplexer. The set of column channels that each IOE can access is different for each IOE. See Figure 15.



**Table 15. 32-Bit FLEX 10K Device IDCODE** *Note (1)*

Device	IDCODE (32 Bits)			
	Version (4 Bits)	Part Number (16 Bits)	Manufacturer's Identity (11 Bits)	1 (1 Bit) (2)
EPF10K10, EPF10K10A	0000	0001 0000 0001 0000	00001101110	1
EPF10K20	0000	0001 0000 0010 0000	00001101110	1
EPF10K30, EPF10K30A	0000	0001 0000 0011 0000	00001101110	1
EPF10K40	0000	0001 0000 0100 0000	00001101110	1
EPF10K50, EPF10K50V	0000	0001 0000 0101 0000	00001101110	1
EPF10K70	0000	0001 0000 0111 0000	00001101110	1
EPF10K100, EPF10K100A	0000	0000 0001 0000 0000	00001101110	1
EPF10K130V	0000	0000 0001 0011 0000	00001101110	1
EPF10K250A	0000	0000 0010 0101 0000	00001101110	1

**Notes:**

- (1) The most significant bit (MSB) is on the left.  
 (2) The least significant bit (LSB) for all JTAG IDCODEs is 1.

FLEX 10K devices include weak pull-ups on JTAG pins.



For more information, see the following documents:

- *Application Note 39 (IEEE 1149.1 (JTAG) Boundary-Scan Testing in Altera Devices)*
- *BitBlaster Serial Download Cable Data Sheet*
- *ByteBlasterMV Parallel Port Download Cable Data Sheet*
- *Jam Programming & Test Language Specification*

**Table 18. FLEX 10K 5.0-V Device Recommended Operating Conditions**

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CCINT}$	Supply voltage for internal logic and input buffers	(3), (4)	4.75 (4.50)	5.25 (5.50)	V
$V_{CCIO}$	Supply voltage for output buffers, 5.0-V operation	(3), (4)	4.75 (4.50)	5.25 (5.50)	V
	Supply voltage for output buffers, 3.3-V operation	(3), (4)	3.00 (3.00)	3.60 (3.60)	V
$V_I$	Input voltage		−0.5	$V_{CCINT} + 0.5$	V
$V_O$	Output voltage		0	$V_{CCIO}$	V
$T_A$	Ambient temperature	For commercial use	0	70	° C
		For industrial use	−40	85	° C
$T_J$	Operating temperature	For commercial use	0	85	° C
		For industrial use	−40	100	° C
$t_R$	Input rise time			40	ns
$t_F$	Input fall time			40	ns

**Table 24. EPF10K50V & EPF10K130V Device DC Operating Conditions** Notes (6), (7)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{IH}$	High-level input voltage		2.0		5.75	V
$V_{IL}$	Low-level input voltage		-0.5		0.8	V
$V_{OH}$	3.3-V high-level TTL output voltage	$I_{OH} = -8$ mA DC (8)	2.4			V
	3.3-V high-level CMOS output voltage	$I_{OH} = -0.1$ mA DC (8) $V_{CCIO} - 0.2$				V
$V_{OL}$	3.3-V low-level TTL output voltage	$I_{OL} = 8$ mA DC (9)			0.45	V
	3.3-V low-level CMOS output voltage	$I_{OL} = 0.1$ mA DC (9)			0.2	V
$I_I$	Input pin leakage current	$V_I = 5.3$ V to $-0.3$ V (10)	-10		10	$\mu$ A
$I_{OZ}$	Tri-stated I/O pin leakage current	$V_O = 5.3$ V to $-0.3$ V (10)	-10		10	$\mu$ A
$I_{CC0}$	$V_{CC}$ supply current (standby)	$V_I =$ ground, no load		0.3	10	mA
		$V_I =$ ground, no load (11)		10		mA

**Table 25. EPF10K50V & EPF10K130V Device Capacitance** (12)

Symbol	Parameter	Conditions	Min	Max	Unit
$C_{IN}$	Input capacitance	$V_{IN} = 0$ V, $f = 1.0$ MHz		10	pF
$C_{INCLK}$	Input capacitance on dedicated clock pin	$V_{IN} = 0$ V, $f = 1.0$ MHz		15	pF
$C_{OUT}$	Output capacitance	$V_{OUT} = 0$ V, $f = 1.0$ MHz		10	pF

**Notes to tables:**

- (1) See the *Operating Requirements for Altera Devices Data Sheet*.
- (2) Minimum DC input voltage is  $-0.5$  V. During transitions, the inputs may undershoot to  $-2.0$  V or overshoot to  $5.75$  V for input currents less than  $100$  mA and periods shorter than  $20$  ns.
- (3) Numbers in parentheses are for industrial-temperature-range devices.
- (4) Maximum  $V_{CC}$  rise time is  $100$  ms.  $V_{CC}$  must rise monotonically.
- (5) EPF10K50V and EPF10K130V device inputs may be driven before  $V_{CCINT}$  and  $V_{CCIO}$  are powered.
- (6) Typical values are for  $T_A = 25^\circ$  C and  $V_{CC} = 3.3$  V.
- (7) These values are specified under the EPF10K50V and EPF10K130V device Recommended Operating Conditions in Table 23 on page 48.
- (8) The  $I_{OH}$  parameter refers to high-level TTL or CMOS output current.
- (9) The  $I_{OL}$  parameter refers to low-level TTL or CMOS output current. This parameter applies to open-drain pins as well as output pins.
- (10) This value is specified for normal device operation. The value may vary during power-up.
- (11) This parameter applies to -1 speed grade EPF10K50V devices, -2 speed grade EPF10K50V industrial temperature devices, and -2 speed grade EPF10K130V devices.
- (12) Capacitance is sample-tested only.

Figure 22 shows the typical output drive characteristics of EPF10K10A, EPF10K30A, EPF10K100A, and EPF10K250A devices with 3.3-V and 2.5-V  $V_{CCIO}$ . The output driver is compliant with the 3.3-V *PCI Local Bus Specification, Revision 2.2* (with 3.3-V  $V_{CCIO}$ ). Moreover, device analysis shows that the EPF10K10A, EPF10K30A, and EPF 10K100A devices can drive a 5.0-V PCI bus with eight or fewer loads.

**Figure 22. Output Drive Characteristics for EPF10K10A, EPF10K30A & EPF10K100A Devices**

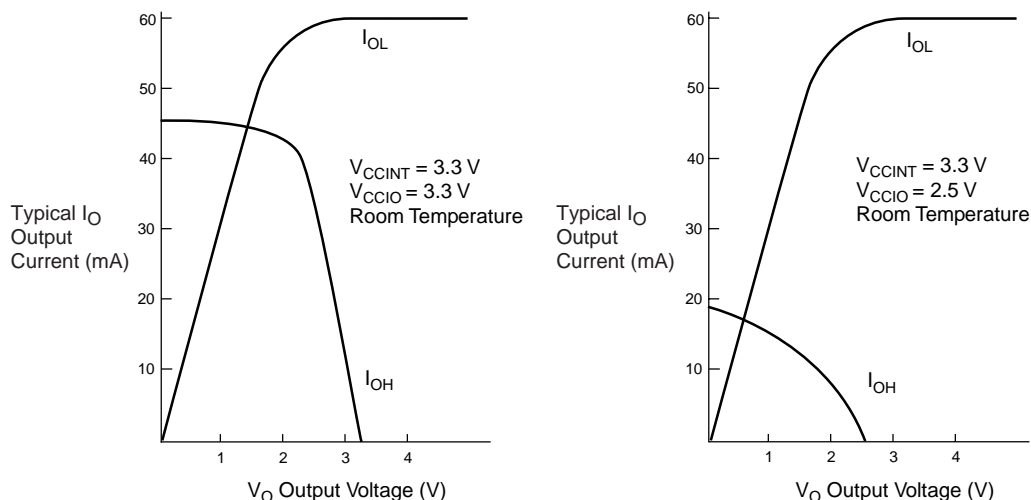
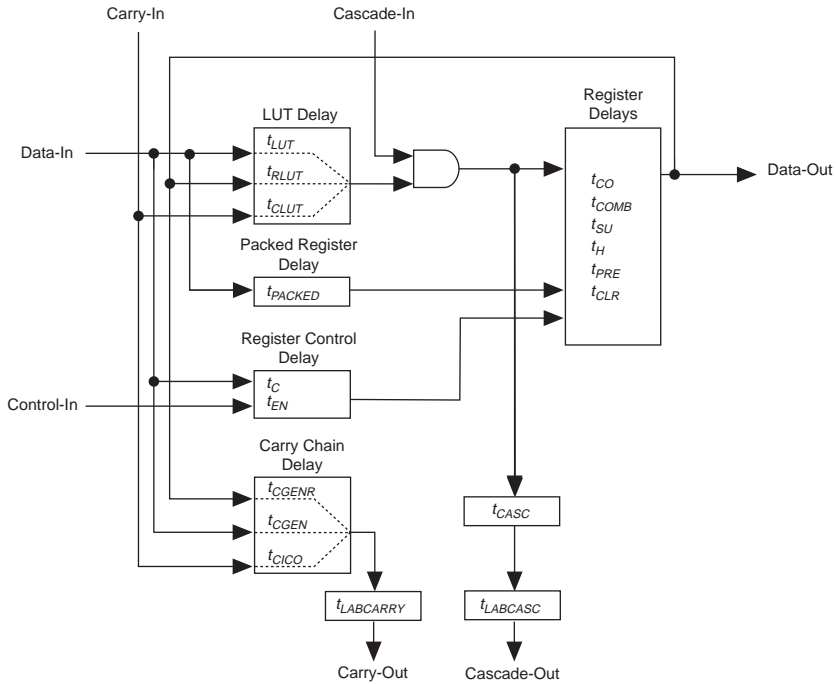


Figure 23 shows the typical output drive characteristics of the EPF10K250A device with 3.3-V and 2.5-V  $V_{CCIO}$ .

Figures 25 through 27 show the delays that correspond to various paths and functions within the LE, IOE, and EAB timing models.

**Figure 25. FLEX 10K Device LE Timing Model**



**Table 42. EPF10K10 & EPF10K20 Device EAB Internal Timing Macroparameters** *Note (1)*

Symbol	-3 Speed Grade		-4 Speed Grade		Unit
	Min	Max	Min	Max	
$t_{EABAA}$		13.7		17.0	ns
$t_{EABRCCOMB}$	13.7		17.0		ns
$t_{EABRCREG}$	9.7		11.9		ns
$t_{EABWP}$	5.8		7.2		ns
$t_{EABWCCOMB}$	7.3		9.0		ns
$t_{EABWCREG}$	13.0		16.0		ns
$t_{EABDD}$		10.0		12.5	ns
$t_{EABDATACO}$		2.0		3.4	ns
$t_{EABDATASU}$	5.3		5.6		ns
$t_{EABDATAH}$	0.0		0.0		ns
$t_{EABWESU}$	5.5		5.8		ns
$t_{EABWEH}$	0.0		0.0		ns
$t_{EABWDSU}$	5.5		5.8		ns
$t_{EABWDH}$	0.0		0.0		ns
$t_{EABWASU}$	2.1		2.7		ns
$t_{EABWAH}$	0.0		0.0		ns
$t_{EABWO}$		9.5		11.8	ns

**Table 51. EPF10K30, EPF10K40 & EPF10K50 Device EAB Internal Timing Macroparameters***Note (1)*

Symbol	-3 Speed Grade		-4 Speed Grade		Unit
	Min	Max	Min	Max	
$t_{EABAA}$		13.7		17.0	ns
$t_{EABRCCOMB}$	13.7		17.0		ns
$t_{EABRCREG}$	9.7		11.9		ns
$t_{EABWP}$	5.8		7.2		ns
$t_{EABWCCOMB}$	7.3		9.0		ns
$t_{EABWCREG}$	13.0		16.0		ns
$t_{EABDD}$		10.0		12.5	ns
$t_{EABDATACO}$		2.0		3.4	ns
$t_{EABDATASU}$	5.3		5.6		ns
$t_{EABDATAH}$	0.0		0.0		ns
$t_{EABWESU}$	5.5		5.8		ns
$t_{EABWEH}$	0.0		0.0		ns
$t_{EABWDSU}$	5.5		5.8		ns
$t_{EABWDH}$	0.0		0.0		ns
$t_{EABWASU}$	2.1		2.7		ns
$t_{EABWAH}$	0.0		0.0		ns
$t_{EABWO}$		9.5		11.8	ns

**Table 61. EPF10K70 Device Interconnect Timing Microparameters** *Note (1)*

Symbol	-2 Speed Grade		-3 Speed Grade		-4 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
$t_{DIN2IOE}$		6.6		7.3		8.8	ns
$t_{DIN2LE}$		4.2		4.8		6.0	ns
$t_{DIN2DATA}$		6.5		7.1		10.8	ns
$t_{DCLK2IOE}$		5.5		6.2		7.7	ns
$t_{DCLK2LE}$		4.2		4.8		6.0	ns
$t_{SAMELAB}$		0.4		0.4		0.5	ns
$t_{SAMEROW}$		4.8		4.9		5.5	ns
$t_{SAMECOLUMN}$		3.3		3.4		3.7	ns
$t_{DIFFROW}$		8.1		8.3		9.2	ns
$t_{TWOROWS}$		12.9		13.2		14.7	ns
$t_{LEPERIPH}$		5.5		5.7		6.5	ns
$t_{LABCARRY}$		0.8		0.9		1.1	ns
$t_{LABCASC}$		2.7		3.0		3.2	ns

**Table 62. EPF10K70 Device External Timing Parameters** *Note (1)*

Symbol	-2 Speed Grade		-3 Speed Grade		-4 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
$t_{DRR}$		17.2		19.1		24.2	ns
$t_{INSU}$ (2), (3)	6.6		7.3		8.0		ns
$t_{INH}$ (3)	0.0		0.0		0.0		ns
$t_{OUTCO}$ (3)	2.0	9.9	2.0	11.1	2.0	14.3	ns

**Table 63. EPF10K70 Device External Bidirectional Timing Parameters** *Note (1)*

Symbol	-2 Speed Grade		-3 Speed Grade		-4 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
$t_{INSUBIDIR}$	7.4		8.1		10.4		ns
$t_{INHBIDIR}$	0.0		0.0		0.0		ns
$t_{OUTCOBIDIR}$	2.0	9.9	2.0	11.1	2.0	14.3	ns
$t_{XZBIDIR}$		13.7		15.4		18.5	ns
$t_{ZXBIDIR}$		13.7		15.4		18.5	ns



**Table 66. EPF10K100 Device EAB Internal Microparameters** *Note (1)*

Symbol	-3DX Speed Grade		-3 Speed Grade		-4 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
$t_{EABDATA1}$		1.5		1.5		1.9	ns
$t_{EABDATA2}$		4.8		4.8		6.0	ns
$t_{EABWE1}$		1.0		1.0		1.2	ns
$t_{EABWE2}$		5.0		5.0		6.2	ns
$t_{EABCLK}$		1.0		1.0		2.2	ns
$t_{EABCO}$		0.5		0.5		0.6	ns
$t_{EABYPASS}$		1.5		1.5		1.9	ns
$t_{EABSU}$	1.5		1.5		1.8		ns
$t_{EABH}$	2.0		2.0		2.5		ns
$t_{AA}$		8.7		8.7		10.7	ns
$t_{WP}$	5.8		5.8		7.2		ns
$t_{WDSU}$	1.6		1.6		2.0		ns
$t_{WDH}$	0.3		0.3		0.4		ns
$t_{WASU}$	0.5		0.5		0.6		ns
$t_{WAH}$	1.0		1.0		1.2		ns
$t_{WO}$		5.0		5.0		6.2	ns
$t_{DD}$		5.0		5.0		6.2	ns
$t_{EABOUT}$		0.5		0.5		0.6	ns
$t_{EABCH}$	4.0		4.0		4.0		ns
$t_{EABCL}$	5.8		5.8		7.2		ns

**Table 73. EPF10K50V Device EAB Internal Microparameters** *Note (1)*

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		-4 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	Min	Max	
$t_{EABDATA1}$		1.7		2.8		3.4		4.6	ns
$t_{EABDATA2}$		4.9		3.9		4.8		5.9	ns
$t_{EABWE1}$		0.0		2.5		3.0		3.7	ns
$t_{EABWE2}$		4.0		4.1		5.0		6.2	ns
$t_{EABCLK}$		0.4		0.8		1.0		1.2	ns
$t_{EABCO}$		0.1		0.2		0.3		0.4	ns
$t_{EABYPASS}$		0.9		1.1		1.3		1.6	ns
$t_{EABSU}$	0.8		1.5		1.8		2.2		ns
$t_{EABH}$	0.8		1.6		2.0		2.5		ns
$t_{AA}$		5.5		8.2		10.0		12.4	ns
$t_{WP}$	6.0		4.9		6.0		7.4		ns
$t_{WDSU}$	0.1		0.8		1.0		1.2		ns
$t_{WDH}$	0.1		0.2		0.3		0.4		ns
$t_{WASU}$	0.1		0.4		0.5		0.6		ns
$t_{WAH}$	0.1		0.8		1.0		1.2		ns
$t_{WO}$		2.8		4.3		5.3		6.5	ns
$t_{DD}$		2.8		4.3		5.3		6.5	ns
$t_{EABOUT}$		0.5		0.4		0.5		0.6	ns
$t_{EABCH}$	2.0		4.0		4.0		4.0		ns
$t_{EABCL}$	6.0		4.9		6.0		7.4		ns

**Table 75. EPF10K50V Device Interconnect Timing Microparameters** *Note (1)*

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		-4 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	Min	Max	
$t_{DIN2IOE}$		4.7		6.0		7.1		8.2	ns
$t_{DIN2LE}$		2.5		2.6		3.1		3.9	ns
$t_{DIN2DATA}$		4.4		5.9		6.8		7.7	ns
$t_{DCLK2IOE}$		2.5		3.9		4.7		5.5	ns
$t_{DCLK2LE}$		2.5		2.6		3.1		3.9	ns
$t_{SAMELAB}$		0.2		0.2		0.3		0.3	ns
$t_{SAMEROW}$		2.8		3.0		3.2		3.4	ns
$t_{SAMECOLUMN}$		3.0		3.2		3.4		3.6	ns
$t_{DIFFROW}$		5.8		6.2		6.6		7.0	ns
$t_{TWOROWS}$		8.6		9.2		9.8		10.4	ns
$t_{LEPERIPH}$		4.5		5.5		6.1		7.0	ns
$t_{LABCARRY}$		0.3		0.4		0.5		0.7	ns
$t_{LABCASC}$		0.0		1.3		1.6		2.0	ns

**Table 76. EPF10K50V Device External Timing Parameters** *Note (1)*

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		-4 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	Min	Max	
$t_{DRR}$		11.2		14.0		17.2		21.1	ns
$t_{INSU}$ (2), (3)	5.5		4.2		5.2		6.9		ns
$t_{INH}$ (3)	0.0		0.0		0.0		0.0		ns
$t_{OUTCO}$ (3)	2.0	5.9	2.0	7.8	2.0	9.5	2.0	11.1	ns

**Table 77. EPF10K50V Device External Bidirectional Timing Parameters** *Note (1)*

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		-4 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	Min	Max	
$t_{INSUBIDIR}$	2.0		2.8		3.5		4.1		ns
$t_{INHBIDIR}$	0.0		0.0		0.0		0.0		ns
$t_{OUTCOBIDIR}$	2.0	5.9	2.0	7.8	2.0	9.5	2.0	11.1	ns
$t_{XZBIDIR}$		8.0		9.8		11.8		14.3	ns
$t_{ZXBIDIR}$		8.0		9.8		11.8		14.3	ns

**Table 100. EPF10K100A Device IOE Timing Microparameters** *Note (1)*

Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	
$t_{IOD}$		2.5		2.9		3.4	ns
$t_{IOC}$		0.3		0.3		0.4	ns
$t_{IOCO}$		0.2		0.2		0.3	ns
$t_{IOCOMB}$		0.5		0.6		0.7	ns
$t_{IOSU}$	1.3		1.7		1.8		ns
$t_{IOH}$	0.2		0.2		0.3		ns
$t_{IOCLR}$		1.0		1.2		1.4	ns
$t_{OD1}$		2.2		2.6		3.0	ns
$t_{OD2}$		4.5		5.3		6.1	ns
$t_{OD3}$		6.8		7.9		9.3	ns
$t_{XZ}$		2.7		3.1		3.7	ns
$t_{ZX1}$		2.7		3.1		3.7	ns
$t_{ZX2}$		5.0		5.8		6.8	ns
$t_{ZX3}$		7.3		8.4		10.0	ns
$t_{INREG}$		5.3		6.1		7.2	ns
$t_{IOFD}$		4.7		5.5		6.4	ns
$t_{INCOMB}$		4.7		5.5		6.4	ns

- $f_{MAX}$  = Maximum operating frequency in MHz  
 $N$  = Total number of logic cells used in the device  
 $tog_{LC}$  = Average percent of logic cells toggling at each clock (typically 12.5%)  
 $K$  = Constant, shown in Tables 114 and 115

**Table 114. FLEX 10K K Constant Values**

Device	K Value
EPF10K10	82
EPF10K20	89
EPF10K30	88
EPF10K40	92
EPF10K50	95
EPF10K70	85
EPF10K100	88

**Table 115. FLEX 10KA K Constant Values**

Device	K Value
EPF10K10A	17
EPF10K30A	17
EPF10K50V	19
EPF10K100A	19
EPF10K130V	22
EPF10K250A	23

This calculation provides an  $I_{CC}$  estimate based on typical conditions with no output load. The actual  $I_{CC}$  should be verified during operation because this measurement is sensitive to the actual pattern in the device and the environmental operating conditions.

To better reflect actual designs, the power model (and the constant  $K$  in the power calculation equations) for continuous interconnect FLEX devices assumes that logic cells drive FastTrack Interconnect channels. In contrast, the power model of segmented FPGAs assumes that all logic cells drive only one short interconnect segment. This assumption may lead to inaccurate results, compared to measured power consumption for an actual design in a segmented interconnect FPGA.

Figure 32 shows the relationship between the current and operating frequency of FLEX 10K devices.